

No.1958A

LA6083D**SANYO**

**J-FET Input
Dual Operational Amplifier**

The LA6083D is a J-FET input dual operational amplifier. Application areas include general-purpose control equipment, measuring equipment (very low current measurement, long-integrating circuit, sample & hold circuit, impedance converter, etc.).

Features

- High slew rate
- High input impedance
- Low input bias current
- Low input offset current
- No phase compensation required
- With offset null pins

Maximum Ratings at $T_a=25^{\circ}\text{C}$

		unit
Maximum Supply Voltage	V_{CC}/V_{EE}	± 18 V
Differential Input Voltage	V_{ID}	± 30 V
Common-Mode Input Voltage	V_{IN} (Note)	± 15 V
Allowable Power Dissipation	P_d max	720 mW
Operating Temperature	T_{opr}	-30 to +85 $^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55 to +125 $^{\circ}\text{C}$

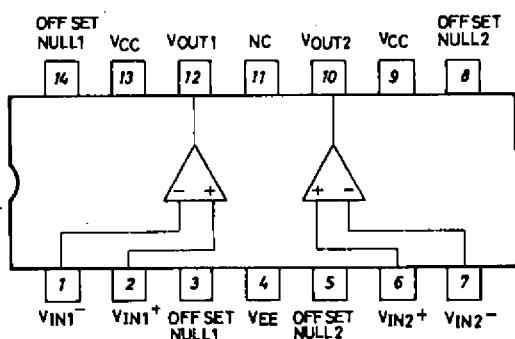
(Note) Allowable in the range of supply voltage. The above value is for $V_{CC}=+15\text{V}$, $V_{EE}=-15\text{V}$.

Operating Characteristics at $T_a=25^{\circ}\text{C}$, $V_{CC}=+15\text{V}$, $V_{EE}=-15\text{V}$

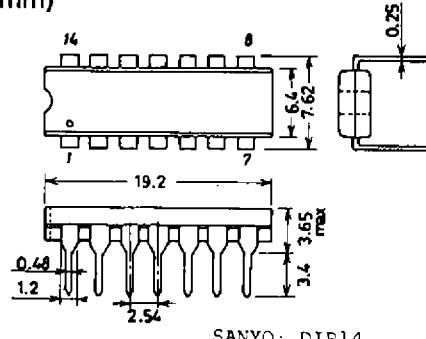
		min	typ	max	unit
Input Offset Voltage	V_{IO} $R_S=50\text{kohms}$	5.0	15.0	mV	
Input Offset Current	I_{IO}	5	200	pA	
Input Bias Current	I_B	30	400	pA	
Common-Mode Input Voltage Range	V_{ICM}	± 10	V		
Common-Mode Rejection Ratio	CMR	70	76	dB	
Large Amplitude Voltage Gain	VG	$R_L \geq 2\text{kohms}$, $V_o=\pm 10\text{V}$	25	200	V/mV
Maximum Output Voltage	V_{opp1}	$R_L \geq 10\text{kohms}$	$\pm 12 \pm 13.5$	V	
	V_{opp2}	$R_L \geq 2\text{kohms}$	$\pm 10 \pm 12$	V	

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Pin Assignment



Package Dimensions 3003A-D14IC
(unit : mm)

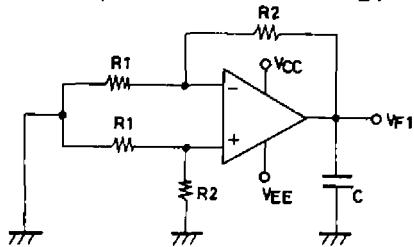


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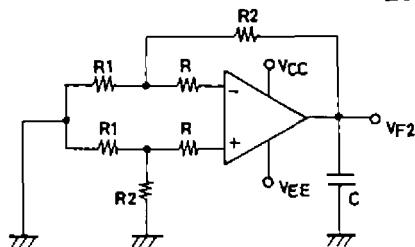
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TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

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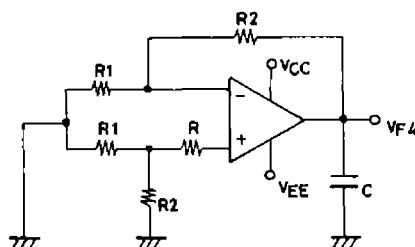
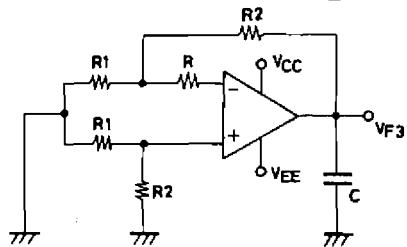
			min	typ	max	unit
Supply Voltage Rejection Ratio	SVR		70	76		dB
Supply Current	I _{CC}	R _L =∞		4	5.6	mA
Gain-Bandwidth Product	f _T	A _V =1		3		MHz
Equivalent Input Noise Voltage	V _{NI}	R _S =100ohms, f=10Hz to 10kHz		4		uVrms
Input Resistance	r _i			10 ¹²		ohm
Channel Separation	ch sep			120		dB
Slew Rate	S·R	R _L =2kohms, C _L =100pF, A _V =1, V _{IN} =10V		13		V/us

Test Circuits**1. Input Offset Voltage V_{IO}**

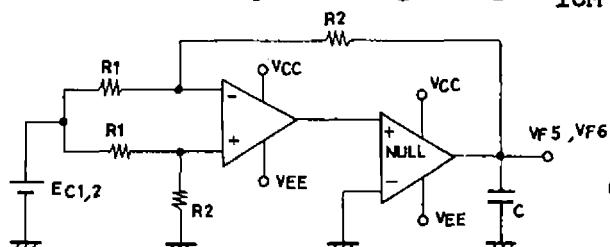
$$V_{IO} = \frac{V_{F1}}{1 + R_2/R_1}$$

2. Input Offset Current I_{IO}

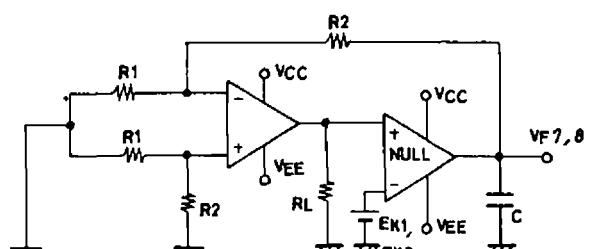
$$I_{IO} = \frac{V_{F2} - V_{F1}}{R(1 + R_2/R_1)}$$

3. Input Bias Current I_B

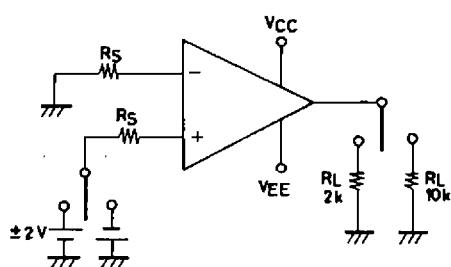
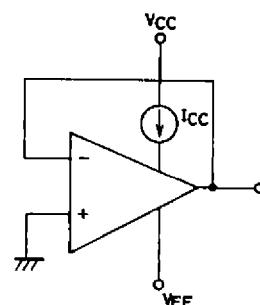
$$I_B = \frac{V_{F4} - V_{F3}}{2R(1 + R_2/R_1)}$$

4. Common-Mode Rejection Ratio CMR**Common-Mode Input Voltage Range V_{ICM}**

$$CMR = 20 \log \left| \frac{(E_{C1} - E_{C2})(1 + R_2/R_1)}{V_{F5} - V_{F6}} \right|$$

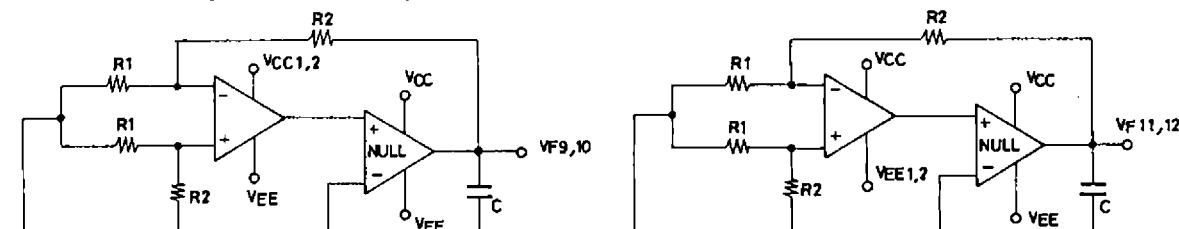
5. Voltage Gain VG

$$VG = \frac{(E_{K1} - E_{K2})(1 + R_2/R_1)}{V_{F8} - V_{F7}}$$

6. Maximum Output Voltage V_{OPP} 7. Supply Current I_{CC} 

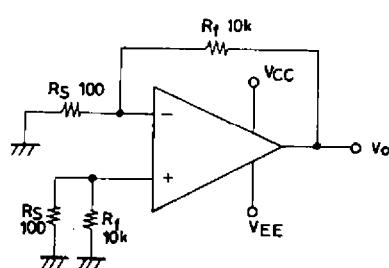
Unit (resistance: Ω)

8. Supply Voltage Rejection Ratio SVR



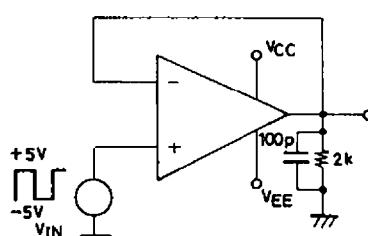
$$SVR (+) = 20 \log \left| \frac{(1 + R_2/R_1)(V_{CC1,2} - V_{CC2})}{V_{F9} - V_{F10}} \right|$$

$$SVR (-) = 20 \log \left| \frac{(1 + R_2/R_1)(V_{EE1,2} - V_{EE2})}{V_{F11} - V_{F12}} \right|$$

9. Equivalent Input Noise Voltage V_{NI} 

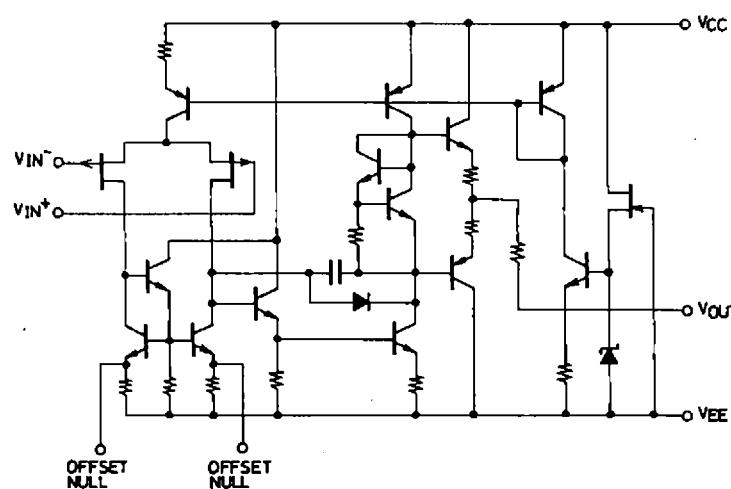
$$V_{NI} = \frac{V_n}{100}$$

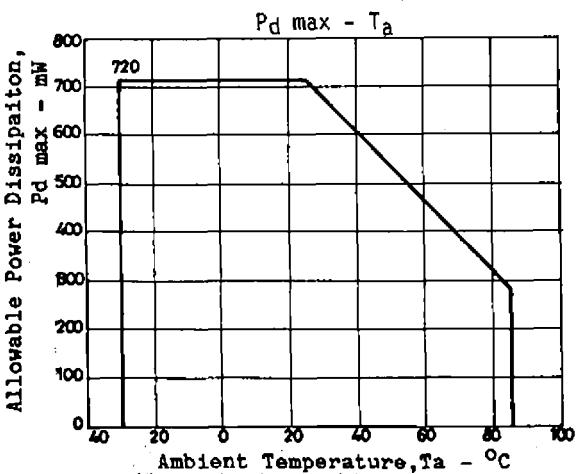
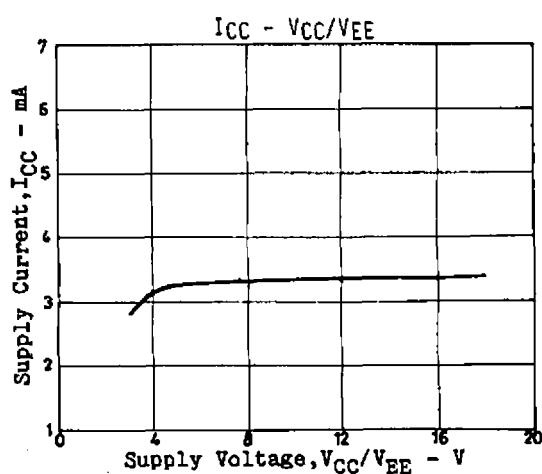
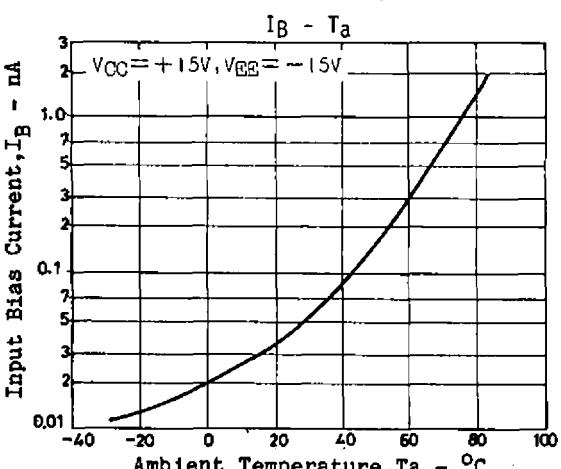
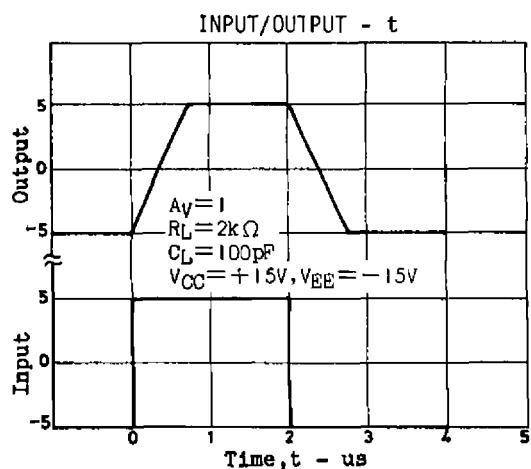
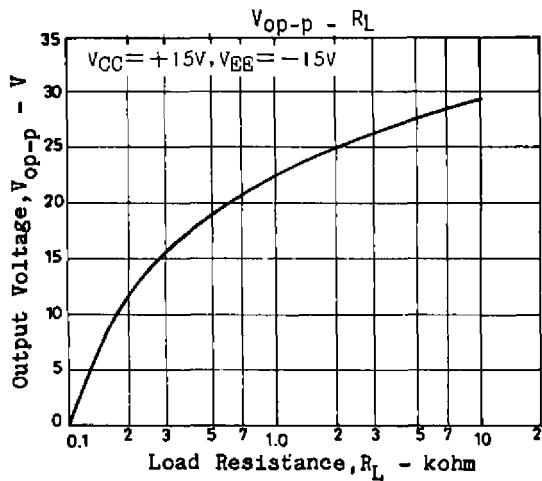
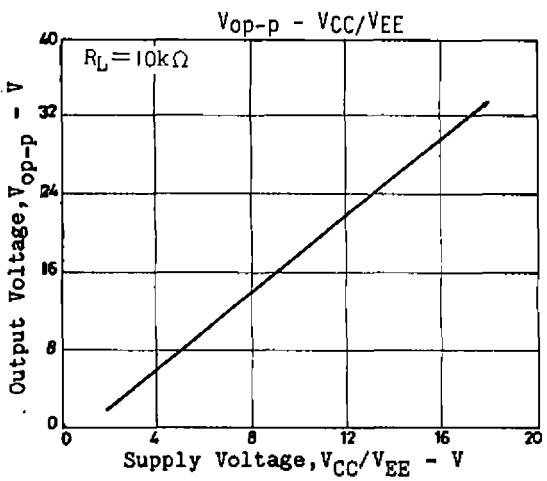
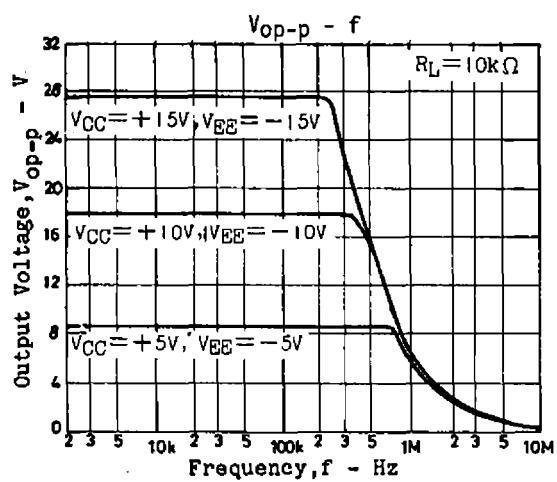
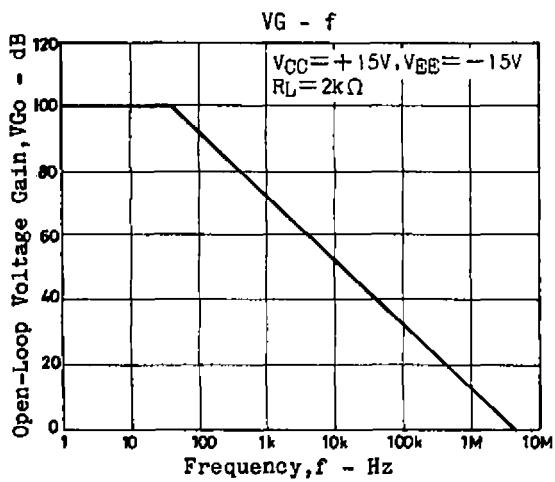
10. Slew Rate SR

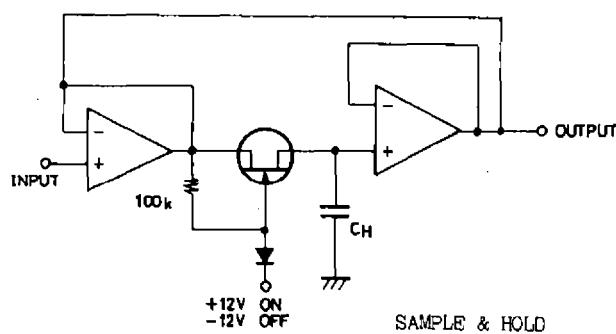
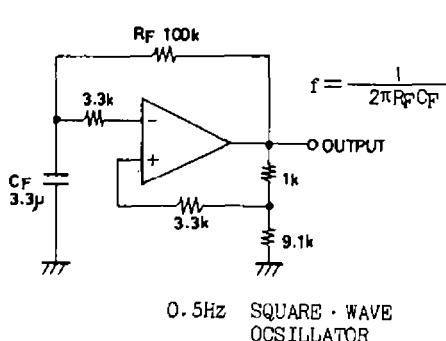


Unit (resistance: Ω capacitance: F)

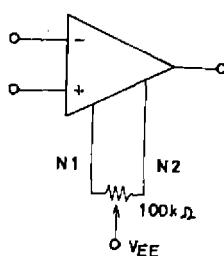
Equivalent Circuit





Sample Application Circuits

Unit (resistance:Ω capacitance:F)

Voltage offset adjust circuit

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